



#### Very Low Power 6-Output PCIe Clock Buffer With On-Chip Termination

#### Features

- → 3.3V supply voltage
- → HCSL input: 100MHz, also support 50MHz, 125MHz or 133.33MHz via SMBus
- → 6 differential low power HCSL outputs with on-chip termination
- → Default  $Z_{OUT} = 100\Omega$
- → Spread spectrum tolerant
- → Individual output enable
- → Programmable Slew rate and output amplitude for each output
- → Differential outputs blocked until PLL is locked
- → Strapping pins or SMBus for configuration
- → Differential output-to-output skew <50ps
- → Very low jitter outputs
- ♦ Differential cycle-to-cycle jitter <50ps
- ♦ PCIe Gen1/Gen2/Gen3/Gen4/Gen5 CC compliant
- ♦ PCIe Gen 2 and 3 SRiS and SRnS compliant
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

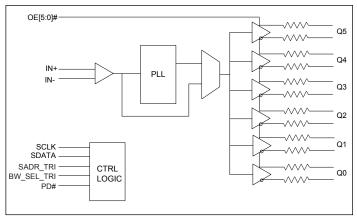
- → Packaging (Pb-free & Green):
  - ♦ 40-lead 5×5mm TQFN

#### Description

The PI6CB33601 is a 6-output very low power PCIe Gen1/Gen2/ Gen3/Gen4/Gen5 clock buffer. It takes a reference input to fanout six 100MHz low power differential HCSL outputs with on-chip terminations. The on-chip termination can save 24 external resistors and make layout easier. Individual OE pin for each output provides easier power management.

It uses Diodes proprietary PLL design to achieve very low jitter that meets PCIe Gen1/Gen2/Gen3/Gen4/Gen5 requirements. Other than PCIe 100MHz support, this device also support Ethernet application with 50MHz, 125MHz and 133.33MHz via SMBus. It provides various options such as different slew rate and amplitude through SMBUS so that users can configure the device easily to get the optimized performance for their individual boards.

#### **Block Diagram**



Notes:

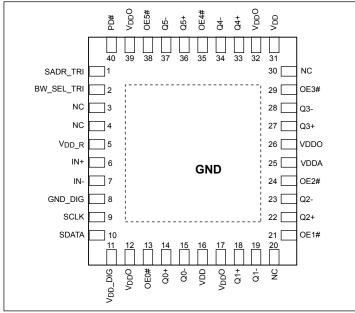
<sup>1.</sup> No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

<sup>2.</sup> See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





### **Pin Configuration**



# **Pin Description**

1		1	ре	Description
1	SADR_TRI	Input	Tri-level	Latch to select SMBus Address. This pin has an internal pull-down
2	BW_SEL_TRI	Input	Tri-level	Latch to select low loop bandwidth, bypass PLL, and high loop band- width. This pin has both internal pull-up and pull-down
3	NC			Internal connected for feedback loop. Do not connect this pin
4	NC			Internal connected for feedback loop. Do not connect this pin
5	V <sub>DD</sub> _R	Power		Power supply for input differential buffers
6	IN+	Input		Differential true clock input
7	IN-	Input		Differential complementary clock input
8	GND_DIG	Power		Ground for digital circuitry
9	SCLK	Input	CMOS	SMBUS clock input, 3.3V tolerant
10	SDATA	Input/ Output	CMOS	SMBUS Data line, 3.3V tolerant
11	V <sub>DD</sub> _DIG	Power		Power supply for digital circuitry, nominal 3.3V
12, 17, 26, 32, 39	V <sub>DDO</sub>	Power		Power supply for differential outputs
13	OE0#	Input	CMOS	Active low input for enabling Q0 pair. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
14	Q0+	Output	HCSL	Differential true clock output
15	Q0-	Output	HCSL	Differential complementary clock output
16, 31	V <sub>DD</sub>	Power		Power supply, nominal 3.3V
18	Q1+	Output	HCSL	Differential true clock output





#### **Pin Description Cont.**

Pin Number	Pin Name	Ту	pe	Description
19	Q1-	Output	HCSL	Differential complementary clock output
20	NC			Do not connect this pin
21	OE1#	Input	CMOS	Active low input for enabling Q1 pair. This pin has an internal pull- down. 1 = disable outputs, 0 = enable outputs
22	Q2+	Output	HCSL	Differential true clock output
23	Q2-	Output	HCSL	Differential complementary clock output
24	OE2#	Input	CMOS	Active low input for enabling Q2 pair. This pin has an internal pull- down. 1 = disable outputs, 0 = enable outputs
25	V <sub>DDA</sub>	Power		Power supply for analog circuitry
27	Q3+	Output	HCSL	Differential true clock output
28	Q3-	Output	HCSL	Differential complementary clock output
29	OE3#	Input	CMOS	Active low input for enabling Q3 pair. This pin has an internal pull- down. 1 = disable outputs, 0 = enable outputs
30	NC			Do not connect this pin
33	Q4+	Output	HCSL	Differential true clock output
34	Q4-	Output	HCSL	Differential complementary clock output
35	OE4#	Input	CMOS	Active low input for enabling Q4 pair. This pin has an internal pull- down. 1 = disable outputs, 0 = enable outputs
36	Q5+	Output	HCSL	Differential true clock output
37	Q5-	Output	HCSL	Differential complementary clock output
38	OE5#	Input	CMOS	Active low input for enabling Q5 pair. This pin has an internal pull- down. 1 =disable outputs, 0 = enable outputs
40	PD#	Input	CMOS	Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin has internal pull-up resistor.
	EPAD	Power		Connect to Ground





#### **SMBus Address Selection Table**

	SADR	Address	+Read/Write Bit
	0	1101011	Х
State of SADR on first application of PD#	М	1101100	Х
	1	1101101	Х

#### **Power Management Table**

PD#	IN	SMBus OE bit	OEn#	Qn+	Qn-	PLL Status
0	Х	X	Х	Low <sup>(2)</sup>	Low <sup>(2)</sup>	Off
1	Running	0	Х	Low <sup>(2)</sup>	Low <sup>(2)</sup>	On <sup>(1)</sup>
1	Running	1	0	Running	Running	On <sup>(1)</sup>
1	Running	1	1	Low <sup>(2)</sup>	Low <sup>(2)</sup>	On <sup>(1)</sup>

Note:

1. If PLL Bypass mode is selected, the PLL will be off and outputs will be running.

2. The output state is set by B11[1:0] (Low/Low default)

#### **PLL Operating Mode Select Table**

BW_SEL_TRI Operating Mode		Byte1 [7:6] Readback	Byte1 [4:3] Control
0	PLL with low Bandwidth	00	00
М	PLL Bypass	01	01
1	PLL with high Bandwidth	11	11

#### **Frequency Select table**

Freq. Select Byte 3 [4:3]	IN (MHz)	Qn (MHz)
00 (default)	100	100
01	50	50
10	125	125
11	133.33	133.33



Note:



PI6CB33601

### **Maximum Ratings**

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +150°	с
Supply Voltage to Ground Potential, VDDxx0.5V to +4.6	V
Input Voltage0.5V to VDD+0.5V, not exceed 4.6	δV
SMBus, Input High Voltage 3.6	5V
ESD Protection (HBM)	V
Junction Temperature	ıax

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## **Operating Conditions**

Temperature =  $T_A$ ; Supply voltages per normal operation conditions; See test circuits for the load conditions

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
V <sub>DD</sub> , V <sub>DDA</sub> , V <sub>DD</sub> _R, V <sub>DD</sub> _DIG	Power Supply Voltage		3.135	3.3	3.465	V
V <sub>DDO</sub>	Output Power Supply Voltage		0.95	1.05-3.3	3.465	V
I <sub>DDA</sub>	Analog Power Supply Current	$V_{DDA}$ , PLL mode, All outputs active @100MHz		21	25	mA
I <sub>DD</sub>	Power Supply Current	$V_{DD} + V_{DD_{DIG}} + V_{DD_{R}}$ , All outputs active @100MHz		34	40	mA
I <sub>DDO</sub>	Power Supply Current for Outputs <sup>(2)</sup>	V <sub>DDO</sub> , PLL mode, All outputs ac- tive @100MHz		22	27	mA
I <sub>DDA_PD</sub>	Analog Power Supply Power Down <sup>(1)</sup> Current	V <sub>DDA</sub> , PLL mode, All outputs LOW/LOW		0.5	1	mA
I <sub>DD_PD</sub>	Power Supply Power Down <sup>(1)</sup> Current	$V_{DD} + V_{DD_DIG +} V_{DD_R}$ , All outputs LOW/LOW		1	2	mA
I <sub>DDO_PD</sub>	Power Supply Current Power Down <sup>(1)</sup> for Outputs	V <sub>DDO</sub> , All outputs LOW/LOW		0.04	0.1	mA
T <sub>A</sub>	Ambient Temperature	Industrial grade	-40		85	°C

Note:

1. Input clock is not running.

2. Outputs drive 5 inch trace.

#### **Input Electrical Characteristics**

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
R <sub>pu</sub>	Internal pull up resistance			120		KΩ
R <sub>dn</sub>	Internal pull down resistance			120		KΩ
L <sub>PIN</sub>	Pin inductance				7	nH





### **SMBus Electrical Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
V <sub>DDSMB</sub>	Nominal bus voltage		2.7		3.6	V
	SMBus, $V_{DDSMB} = 3.3V$	2.1		3.6		
V <sub>IHSMB</sub>	SMBus Input High Voltage	SMBus, V <sub>DDSMB</sub> < 3.3V	0.65 V <sub>DDSMB</sub>			V
	SMBus Input Low Voltage	SMBus, V <sub>DDSMB</sub> = 3.3V			0.8	V
VILSMB		SMBus, V <sub>DDSMB</sub> < 3.3V			0.8	
I <sub>SMBSINK</sub>	SMBus sink current	SMBus, at V <sub>OLSMB</sub>	4			mA
VOLSMB	SMBus Output Low Voltage	SMBus, at I <sub>SMBSINK</sub>			0.4	V
f <sub>MAXSMB</sub>	SMBus operating frequency	Maximum frequency			500	kHz
t <sub>RMSB</sub>	SMBus rise time	(Max $\mathrm{V_{IL}}$ - 0.15) to (Min $\mathrm{V_{IH}}$ + 0.15)			1000	ns
t <sub>FMSB</sub>	SMBus fall time	(Min $\mathrm{V_{IH}}$ + 0.15) to (Max $\mathrm{V_{IL}}$ - 0.15)			300	ns

## **LVCMOS DC Electrical Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
V <sub>IH</sub>	Input High Voltage	Single-ended inputs, except SMBus	0.75 V <sub>DD</sub>		V <sub>DD</sub> +0.3	V
VIM	Input Mid Voltage	SADR_TRI, BW_SEL_TRI	$0.4 V_{DD}$	$0.5 V_{\rm DD}$	$0.6V_{\rm DD}$	V
V <sub>IL</sub>	Input Low Voltage	Single-ended inputs, except SMBus	-0.3		0.25 V <sub>DD</sub>	V
I <sub>IH</sub>	Input High Current	Single-ended inputs, $V_{IN} = V_{DD}$			5	μA
I <sub>IL</sub>	Input Low Current	Single-ended inputs, $V_{IN} = 0V$	-5			μA
I <sub>IH</sub>	Input High Current	Single-ended inputs with pull up / pull down resistor, $V_{IN} = V_{DD}$			50	μA
I <sub>IL</sub>	Input Low Current	Single-ended inputs with pull up / pull down resistor, $V_{IN} = 0V$	-50			μA
C <sub>IN</sub>	Input Capacitance		1.5		5	pF





## **LVCMOS AC Electrical Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
t <sub>OELAT</sub>	Output enable latency	Q start after OE# assertion Q stop after OE# deassertion	1		3	clocks
t <sub>PDLAT</sub>	PD# de-assertion	Differential outputs enable after PD# de- assertion		20	300	us

#### HCSL Input Characteristics<sup>(1)</sup>

Temperature =  $T_A$ ; Supply voltages per normal operation conditions; See test circuits for the load conditions

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
V <sub>IHDIF</sub>	Diff. Input High Voltage <sup>(3)</sup>	IN+, IN-, single-end measurement	600	800	1150	mV
V <sub>ILDIF</sub>	Diff. Input Low Voltage <sup>(3)</sup>	IN+, IN-, single-end measurement	-300	0	300	mV
V <sub>COM</sub>	Diff. Input Common Mode Voltage		150		900	mV
V <sub>SWING</sub>	Diff. Input Swing Voltage	Peak to peak value (V <sub>IHDIF</sub> - V <sub>ILDIF)</sub>	300		2900	mV
f <sub>INBP</sub>	Input Frequency	PLL Bypass mode	1		200	MHz
f <sub>IN100</sub>	Input Frequency	100MHz PLL	99.9	100	100.1	MHz
f <sub>IN133</sub>	Input Frequency	133MHz PLL	133.2	133.33	133.46	MHz
f <sub>IN125</sub>	Input Frequency	125MHz PLL	124.87	125	125.12	MHz
f <sub>IN50</sub>	Input Frequency	50MHz PLL	49.95	50	50.05	MHz
f <sub>MODI-</sub> PCIe	Input SS Modulation Freq. PCIe	Allowable frequency for PCIe applications (Triangular Modulation)	30		33	kHz
f <sub>MODIN-</sub> non-PCIe	Input SS Modulation Freq. non-PCIe	Allowable frequency for non-PCIe applica- tions (Triangular Modulation)	0		46	kHz
t <sub>STAB</sub>	Clock stabilization	From $V_{DD}$ Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.75	1.0	ms
t <sub>RF</sub>	Diff. Input Slew Rate <sup>(2)</sup>	Measured differentially	0.4			V/ns
I <sub>IN</sub>	Diff. Input Leakage Current	$V_{IN} = V_{DD}, V_{IN} = GND$	-5	0.01	5	uA
t <sub>DC</sub>	Diff. Input Duty Cycle	Measured differentially	45		55	%
tj <sub>c-c</sub>	Diff. Input Cycle to cycle jitter	Measured differentially			125	ps

#### Note:

1. Guaranteed by design and characterization, not 100% tested in production

2. Slew rate measured through +/-75mV window centered around differential zero

3. The device can be driven by a single-ended clock by driving the true clock and biasing the complement clock input to the V bias, where V bias is  $(V_{IH}-V_{IL})/2$ 





## **HCSL Output Characteristics**

Temperature = T<sub>A</sub>; Supply voltages per normal operation conditions; See test circuits for the load conditions

Symbol	Parameters	Condition	Min.	Тур.	Max.	Units
V <sub>OH</sub>	Output Voltage High <sup>(1)</sup>	Statistical measurement on single-ended	660	784	850	mV
VOL	Output Voltage Low <sup>(1)</sup>	signal using oscilloscope math function	-150		150	mV
VOMAX	Output Voltage Maximum <sup>(1)</sup>	Measurement on single ended signal using		816	1150	mV
V <sub>OMIN</sub>	Output Voltage Minimum <sup>(1)</sup>	absolute value	-300	-42		mV
V <sub>OC</sub>	Output Cross Voltage <sup>(1,2,4)</sup>		250	430	550	mV
DV <sub>OC</sub>	V <sub>OC</sub> Magnitude Change <sup>(1,2,5)</sup>			12	140	mV

#### Note:

1. At default SMBUS amplitude settings

2. Guaranteed by design and characterization, not 100% tested in production

3. Measured from differential waveform

4. This one is defined as voltage where Q + = Q- measured on a component test board and only applied to the differential rising edge

5. The total variation of all Vcross measurements in any particular system. This is a subset of Vcross\_min/max allowed.

## **HCSL Output AC Characteristics**

Temperature =  $T_A$ ; Supply voltages per normal operation conditions; See test circuits for the load conditions

Symbol	Parameters	Condition	Min.	Тур.	Max.	Units
f <sub>OUT</sub>	Output Frequency		50	100	133.33	MHz
DIAZ	PLL bandwidth <sup>(1,8)</sup>	-3dB point in High Bandwidth Mode	1.3	3.2	3.6	MHz
BW	PLL bandwidth	-3dB point in Low Bandwidth Mode	0.7	1.7	1.9	MHz
tj <sub>peak</sub>	PLL Jitter Peaking <sup>(1)</sup>	Peak pass band gain		0.8	2	dB
4	Slew rate <sup>(1,2,3)</sup>	Scope averaging on fast setting	2.5	3.2	4.0	V/ns
t <sub>RF</sub>	Slew rate (1,2,5)	Scope averaging on slow setting	2.2	3.0	3.7	V/ns
Dt <sub>RF</sub>	Slew rate matching <sup>(1,2,4)</sup>	Scope averaging on		7	15	%
t <sub>SKEW</sub>	Output Skew <sup>(1,2)</sup>	Averaging on, $V_T = 50\%$		21	50	ps
	D. (11	PLL Bypass mode, $V_T = 50\%$	2000	2500	3000	ps
tpdelay	Propagation delay	PLL mode, V <sub>T</sub> = 50%	-200	90	200	ps
t <sub>DC</sub>	Duty Cycle <sup>(1,2)</sup>	Measured differentially, PLL Mode	45	50	55	%
t <sub>DCD</sub>	Duty Cycle Distortion <sup>(1,7)</sup>	Measured differentially, PLL Bypass Mode at 100MHz	-3.5	0	3.5	%
t <sub>DCD</sub>	Duty Cycle Distortion <sup>(1,7)</sup>	Measured differentially, SE input, PLL Bypass Mode at 100MHz	-10	0	10	%
	(12)	PLL mode		14	50	ps
tj <sub>c-c</sub>	Cycle to cycle jitter <sup>(1,2)</sup>	Additive jitter, Bypass mode		0.1	1	ps





### **HCSL Output AC Characteristics (jitter)**

Symbol	Parameters	Condition	Min.	Тур.	Max.	Spec Limit	Units
		PCIe Gen 1 <sup>(6)</sup>		25	35	86	ps(p-p)
		PCIe Gen 2 Low Band, 10kHz < f < 1.5MHz		0.6	0.8	3	ps
		PCIe Gen 2 High Band, 1.5MHz < f < Nyquist (50MHz)		0.7	1.2	3.1	ps
	ntegrated phase jitter PLL PCIe Gen 3 (PLL BW of 2-4 or 2-5MHz, CDR =10MHz)		0.25	0.4	1	ps	
	mode (RMS) <sup>(1,5)</sup>	PCIe Gen 4 (PLL BW of 2-4 or 2-5MHz, CDR =10MHz)		0.25	0.4	0.5	ps
		PCIe Gen 5 (PLL BW of 500k to 1.8MHz. CDR =20MHz) <sup>(11)</sup>		0.07	0.12	0.15	ps
		125MHz, 1.5MHz to 20MHz, -20dB/ decade Rollover < 1.5MHz, -40dB/de- cade rolloff > 10MHz		0.15	0.3		ps
		133.33MHz		0.15	0.3		ps
		PCIe Gen 1		0.01	0.05		ps(p-p)
		PCIe Gen 2 Low Band, 10kHz < f < 1.5MHz		0.01	0.05		ps
		PCIe Gen 2 High Band, 1.5MHz < f < Nyquist (50MHz)		0.01	0.05		ps
		PCIe Gen 3 (PLL BW of 2-4 or 2-5MHz, CDR =10MHz)		0.01	0.05		ps
tj <sub>PHASEA</sub>	Additive Integrated phase jitter (RMS) <sup>(1,5,10)</sup>	PCIe Gen 4 (PLL BW of 2-4 or 2-5MHz, CDR =10MHz)		0.01	0.05		ps
		PCIe Gen 5 (PLL BW of 500k to 1.8MHz. CDR =20MHz) <sup>(11)</sup>		0.01	0.05		ps
		125MHz, 1.5MHz to 20MHz, -20dB/ decade Rollover < 1.5MHz, -40dB/de- cade rolloff > 10MHz		0.01	0.05		ps
		133.33MHz		0.01	0.05		ps
		156.25MHz 12k to 20MHz		0.01	0.05		ps

#### Note:

1. Guaranteed by design and characterization, not 100% tested in production

2. Measured from differential waveform

3. Slew rate is measured through the Vswing voltage range centered around differential 0V, within +/-150mV window

4. Slew rate matching is measured through +/-75mV window centered around differential zero

5. See http://www.pcisig.com for complete specs

6. Sample size of at least 100k cycles. This can be extrapolated to 108ps pk-pk @ 1M cycles for a BER of  $10^{-12}$ 

7. Duty cycle distortion is the difference in duty cycle between the output and input clock when the device is operated in the PLL bypass mode

8. The Min and Max values of each BW setting track each other, low BW max will never occur with high BW min

9. Applies to all differential outputs

10. For additive jitter RMS value is calculated by the following equation = SQRT  $[(total jitter)^{*2} - (input jitter)^{*2}]$ 

11. PCIe Gen 5 v0.9 specification





## **SMBus Serial Data Interface**

PI6CB33601 is a slave only device that supports block read and block write protocol using a single 7-bit address and read/write bit as shown below.

Read and write block transfers can be stopped after any complete byte transfer.

#### **Address Assignment**

A6	A5	A4	A3	A2	A1	A0	R/W
1	1	0	1	See SBMus Add	dress Selection ta	ble	1/0

Note: SMBus address is latched on SADR pin

#### How to Write

1 bit	7 bits	1 bit	1 bit	8 bits	1 bit	8 bits	1 bit	8 bits	1 bit	8 bits	1 bit	1 bit
Start bit	Add.	W(0)	Ack	Beginning Byte loca- tion = N	Ack	Data Byte count = X	Ack	Beginning Data Byte (N)	Ack	 Data Byte (N+X-1)	Ack	Stop bit

#### How to Read

1 bit	7 bits	1 bit	1 bit	8 bits	1 bit	1 bit	7 bits	1 bit	1 bit	8 bit	ts	1 bit	<b>8 b</b> i	its	1 bit
Start bit	Address	W(0)	Ack	Beginning Byte loca- tion = N	Ack	Repeat Start bit	Address	R(1)	Ack		Byte t = X	Ack		inning a Byte	Ack
											8 bit	5		1 bit	1 bit
											Data l (N+X-			NAck	Stop bit





#### **Byte 0: Output Enable Register**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	Q5_OE	Q5 output enable	RW	1		
6	Q4_OE	Q4 output enable	RW	1		
5	Reserved			0		
4	Q3_OE	Q3 output enable	RW	1	C D11[1.0]	D: ( 1
3	Q2_OE	Q2 output enable	RW	1	See B11[1:0]	Pin control
2	Q1_OE	Q1 output enable	RW	1		
1	Reserved			0		
0	Q0_OE	Q0 output enable	RW	1		

Note:

1. A low on these bits will override the OE# pins and force the differential outputs to the state indicated by B11[1:0] (Low/Low default)

#### Power Up Condition Bit **Control Function** Description Type 0 1 7 PLLMODERB1 PLL Mode Readback Bit1 R Latch See PLL Operating Mode Table R 6 PLLMODERB0 PLL Mode Readback Bit0 Latch Values in Values in RW PLLMODE\_SWCTR Enable SW control of PLL Mode 0 5 B1[7:6] set PLL B1[4:3] set PLL Mode Mode RW<sup>(1)</sup> 0 4 PLLMODE1 PLL Mode control Bit1 See PLL Operating Mode Table $RW^{(1)}$ PLLMODE0 3 PLL Mode control Bit0 0 2 Reserved 1 1 1 Amplitude1 RW '00' = 0.6V, '01' = 0.68V, '10' = Control output amplitude 0.75V, '11' = 0.85V 0 Amplitude0 RW 0

### Byte 1: PLL Operating Mode and Output Amplitude Control Register

Note:

1. B1[5] must be set to a 1 for these bits to have any effect on the part





### **Byte 2: Differential Output Slew Rate Control Register**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	SLEWRATECTR_Q5	Control slew rate of Q5	RW	1	Slow setting	Fast setting
6	SLEWRATECTR_Q4	Control slew rate of Q4	RW	1	Slow setting	Fast setting
5	Reserved			1		
4	SLEWRATECTR_Q3	Control slew rate of Q3	RW	1	Slow setting	Fast setting
3	SLEWRATECTR_Q2	Control slew rate of Q2	RW	1	Slow setting	Fast setting
2	SLEWRATECTR_Q1	Control slew rate of Q1	RW	1	Slow setting	Fast setting
1	Reserved			1		
0	SLEWRATECTR_Q0	Control slew rate of Q0	RW	1	Slow setting	Fast setting

### **Byte 3: Frequency Select Control Register**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	Reserved			1		
6	Reserved			1		
5	FREQ_SEL_EN	Enable SW selection of frequency	RW	0	SW Freq. selection disabled	SW Freq. selection enabled
4	FSEL1	Freq. Select Bit 1	RW <sup>(1)</sup>	0	с . <b>Г</b>	
3	FSEL0	Freq. Select Bit 0	RW <sup>(1)</sup>	0	See Frequency	Select Table
2	Reserved			1		
1	Reserved			1		
0	SLEWRATESEL FB	Adjust Slew Rate of Feedback signal	RW	1	Slow setting	Fast setting

#### Note:

1. B3[5] must be set to a 1 for these bits to have any effect on the part

#### **Byte 4: Reserved**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7:0	Reserved			1		





## **Byte 5: Revision and Vendor ID Register**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	RID3		R	0		
6	RID2		R	0	0000	
5	RID1	Revision ID	R	0	rev = 0000	
4	RID0		R	0		
3	PVID3		R	0		
2	PVID2		R	0	D: 1 0011	
1	PVID1	Vendor ID	R	1	Diodes = 0011	
0	PVID0		R	1		

### Byte 6: Device Type/Device ID Register

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	DTYPE1		RW	0	'00' = CG, '01' =	ZDB,
6	DTYPE0	Device type	RW	1	'10' = Reserve, '11' = ZDB	
5	DID5		RW	0	- - 000110 binary, 06Hex	
4	DID4		RW	0		
3	DID3	Device ID	RW	0		
2	DID2	Device ID	RW	1		
1	DID1		RW	1		
0	DID0		RW	0		

#### **Byte 7: Reserved**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7:0	Reserved			0x08		

#### Byte 8 and 9: Reserved

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7:0	Reserved			B8 = 0x36		
7.0	Reserved			B9 = 0x00		





#### **Byte 10: PD Restore**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	Reserved		RW	1		
6	PD Restore	PD Restore to default configuration	RW	1	Clear PD Config	Keep PD Config
5:0	Reserved		R	0		

#### **Byte 11: Stop Control**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	FB_imp[1]	Feedback Zout	RW	1	00=Reserved	10=100 DIF Zout
6	FB_imp[0]		RW	0	01=85 DIF Zout	11 = Reserved
5:2	Reserved			0		
1	STP1	True/ Compliment DIF Output Disable Sate	RW	0	00= Low/Low	10= High/ Low
0	STP0		RW	0	01= HiZ/HiZ	11= Low/High

#### **Byte 12: Impedance Control**

Bit	Control Function	Description	Туре	Power Up Condition	0	1		
7	Q2_Zout1	Q2 Zout	RW	_				
6	Q2_Zout0	Q2 Zout	RW					
5	Q1_Zout1	Q1 Zout	RW		00 = Reserved 01 = 85Ω			
4	Q1_Zout0	Q1 Zout	RW					
3	Reserved		RW	10	$10 = 100\Omega$			
2	Reserved		RW		11 = Reserved			
1	Q0_Zout1	Q0 Zout	RW					
0	Q0_Zout0	Q0 Zout	RW					





#### **Byte 13: Impedance Control** Power Up Condition Bit **Control Function** Description Туре 0 1 7 Q5\_Zout1 Q5 Zout RW Q5\_Zout0 6 Q5 Zout RW 5 Q4\_Zout1 RW Q4 Zout 00 = Reserved4 Q4\_Zout0 Q4 Zout RW $01 = 85\Omega$ 10 3 RW $10 = 100\Omega$ Reserved 2 Reserved RW 11 = Reserved 1 Q3\_Zout1 Q3 Zout RW 0 Q3\_Zout0 Q3 Zout RW

### **Byte 14: OE Termination Control**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	OE2_term1	OE2 Pull up or down	RW	0	00=None	10= Pullup
6	OE2_term0	OE2 Pull up or down	RW	1	01=Pulldown	11=Pullup and Down
5	OE1_term1	OE1 Pull up or down	RW	0	00=None	10= Pullup
4	OE1_term0	OE1 Pull up or down	RW	1	01=Pulldown	11=Pullup and Down
3	Reserved			0		
2	Reserved			1		
1	OE0_term1	OE0 Pull up or down	RW	0	00=None	10= Pullup
0	OE0_term0	OE0 Pull up or down	RW	1	01=Pulldown	11=Pullup and Down

## **Byte 15: OE Termination Control**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	OE5_term1	OE5 Pull up or down	RW	0	00=None	10= Pullup
6	OE5_term0	OE5 Pull up or down	RW	1	01=Pulldown	11=Pullup and Down
5	OE4_term1	OE4 Pull up or down	RW	0	00=None	10= Pullup
4	OE4_term0	OE4 Pull up or down	RW	1	01=Pulldown	11=Pullup and Down
3	Reserved			0		
2	Reserved			1		
1	OE3_term1	OE3 Pull up or down	RW	0	00=None	10= Pullup
0	OE3_term0	OE3 Pull up or down	RW	1	01=Pulldown	11=Pullup and Down





### **Byte 16: Power Good Termination Control**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7:2	Reserved			0x00		
1	PWRGD_PD1		RW	1	00=None	10= Pullup
0	PWRGD_PD0	Clock Power Good and Power Down Pull up or Pull down	RW	0	01=Pulldown	11=Pullup and Down

#### Byte 17: Reserved

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7:0	Reserved			0		

#### **Byte 18: Enable Pin Control**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7	OE5_Enable	Sets Enable High or Low	RW	0	Enable = Low	Enable = High
6	OE4_Enable	Sets Enable High or Low	RW	0	Enable = Low	Enable = High
5	Reserved			0		
4	OE3_Enable	Sets Enable High or Low	RW	0	Enable = Low	Enable = High
3	OE2_Enable	Sets Enable High or Low	RW	0	Enable = Low	Enable = High
2	OE1_Enable	Sets Enable High or Low	RW	0	Enable = Low	Enable = High
1	Reserved			0		
0	OE0_Enable	Sets Enable High or Low	RW	0	Enable = Low	Enable = High

#### **Byte 19: Power Down Pin Control**

Bit	Control Function	Description	Туре	Power Up Condition	0	1
7:1	Reserved			0		
0	PWRGD_PD	PWRGD_PD Active via Pull up or Pull down	RW	0	Power Down = Low	Power Down = High





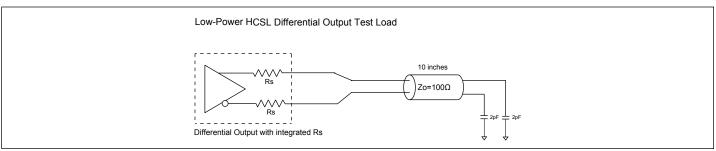


Figure 1. Low Power HCSL Test Circuit

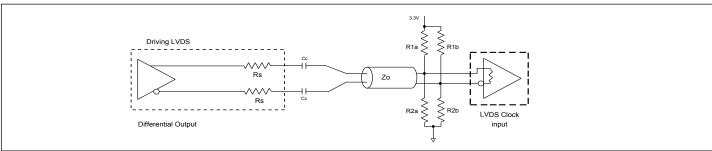
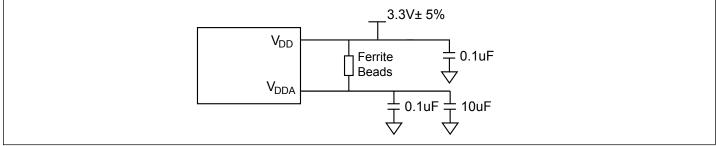
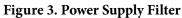


Figure 2. Differential Output driving LVDS

# **Alternate Differential Output Terminations**

Component	Receiver with termination	Receiver without termination	Unit
$R_{1a}, R_{1b}$	10,000	140	Ω
R <sub>2a</sub> , R <sub>2b</sub>	5,600	75	Ω
C <sub>C</sub>	0.1	0.1	μF
V <sub>CM</sub>	1.2	1.2	V









### **Thermal Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
$\theta_{JA}$	Thermal Resistance Junction to Ambient	Still air			29.91	°C/W
$\theta_{JC}$	Thermal Resistance Junction to Case				15.92	°C/W

## **Part Marking**

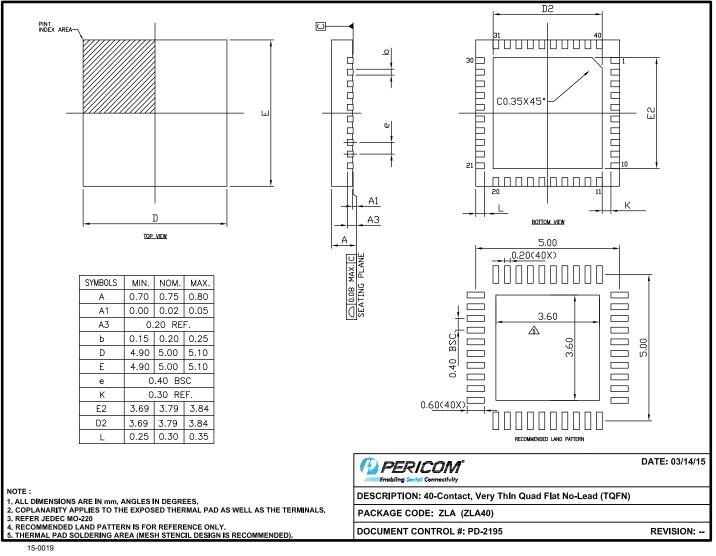


YY: Year WW: Workweek 1st X: Assembly Code 2nd X: Fab Code





# Packaging Mechanical: 40-TQFN (ZLA)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

#### **Ordering Information**

Ordering Code	Package Code	Package Description	Pin 1 Location
PI6CB33601ZLAIEX	ZLA	40-Contact, Very Thin Quad Flat No-Lead (TQFN)	Top Right Corner
PI6CB33601ZLAIEX-13R	ZLA	40-Contact, Very Thin Quad Flat No-Lead (TQFN)	Top Left Corner

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel

6. For packaging details, go to our website at: https://www.diodes.com/assets/MediaList-Attachments/Diodes-Package-Information.pdf





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